

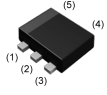
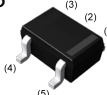
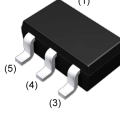
<For Tr1(PNP)>

Parameter	Value
V_{CEO}	-50V
I_C	-150mA

<For Tr2(NPN)>

Parameter	Value
V_{CEO}	50V
I_C	150mA

● Outline

<p>SOT-553</p>  <p>EMY1 (EMT5)</p>	<p>SOT-353</p>  <p>UMY1N (UMT5)</p>
<p>SOT-25</p>  <p>FMY1A (SMT5)</p>	

● Features

- 1) Included a 2SA1037AK and a 2SC2412K transistor in a EMT, UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) PNP and NPN transistors have common emitters.
- 4) Mounting cost and area can be cut in half.

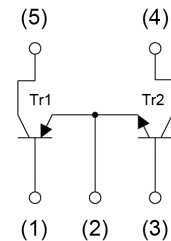
● Application

GENERAL PURPOSE SMALL SIGNAL AMPLIFIER

● Inner circuit

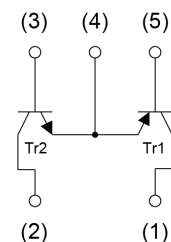
EMY1 / UMY1N

- (1) Tr1 Base
- (2) Tr1/Tr2 Emitter
- (3) Tr2 Base
- (4) Tr2 Collector
- (5) Tr1 Collector



FMY1A

- (1) Tr1 Collector
- (2) Tr2 Collector
- (3) Tr2 Base
- (4) Tr1/Tr2 Emitter
- (5) Tr1 Base



● Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
EMY1	SOT-553 (EMT5)	1616	T2R	180	8	8000	Y1
UMY1N	SOT-353 (UMT5)	2021	TR	180	8	3000	Y1
FMY1A	SOT-25 (SMT5)	2928	T148	180	8	3000	Y1

● Absolute maximum ratings (T_a = 25°C)

Parameter		Symbol	Tr1(PNP)	Tr2(NPN)	Unit
Collector-base voltage		V _{CBO}	-60	60	V
Collector-emitter voltage		V _{CEO}	-50	50	V
Emitter-base voltage		V _{EBO}	-6	7	V
Collector current		I _C	-150	150	mA
Power dissipation	EMY1/ UMY1N	P _D ^{*1*2}	150		mW/Total
	FMY1A	P _D ^{*1*3}	300		mW/Total
Junction temperature		T _j	150		°C
Range of storage temperature		T _{stg}	-55 to +150		°C

● Electrical characteristics (T_a = 25°C) <For Tr1(PNP)>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV _{CBO}	I _C = -50μA	-60	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -50μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -60V	-	-	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = -50mA, I _B = -5mA	-	-	-500	mV
DC current gain	h _{FE}	V _{CE} = -6V, I _C = -1mA	120	-	560	-
Transition frequency	f _T	V _{CE} = -12V, I _E = 2mA, f = 100MHz	-	140	-	MHz
Output capacitance	C _{ob}	V _{CB} = -12V, I _E = 0mA, f = 1MHz	-	4.0	5.0	pF

● Electrical characteristics (T_a = 25°C) <For Tr2(NPN)>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	60	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 50μA	7	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 60V	-	-	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 7V	-	-	100	nA
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 50mA, I _B = 5mA	-	-	400	V
DC current gain	h _{FE}	V _{CE} = 6V, I _C = 1mA	120	-	560	-
Transition frequency	f _T	V _{CE} = 12V, I _E = -2mA, f = 100MHz	-	180	-	MHz
Output capacitance	C _{ob}	V _{CB} = 12V, I _E = 0A, f = 1MHz	-	2.0	3.5	pF

- *1 Each terminal mounted on a referenve land.
- *2 120mW per element must not be exceeded.
- *3 200mW per element must not be exceeded.

●Electrical characteristic curves($T_a=25^{\circ}\text{C}$ <For Tr1(PNP)>

Fig.1 Ground Emitter Propagation Characteristics

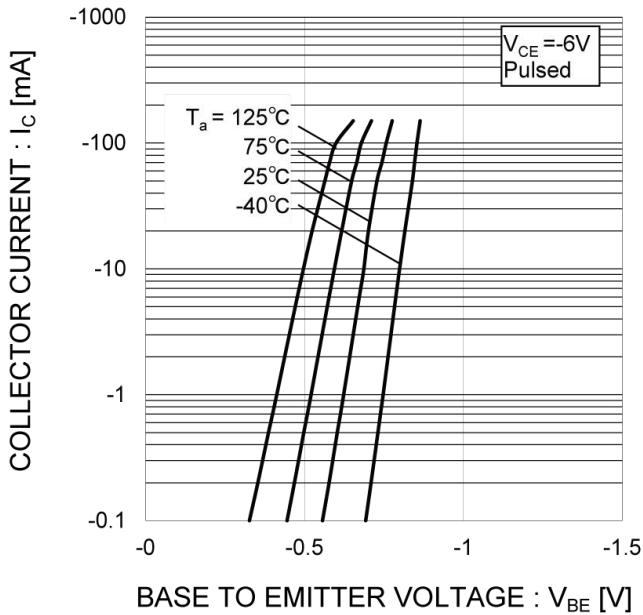


Fig.2 Grounded Emitter Output Characteristics

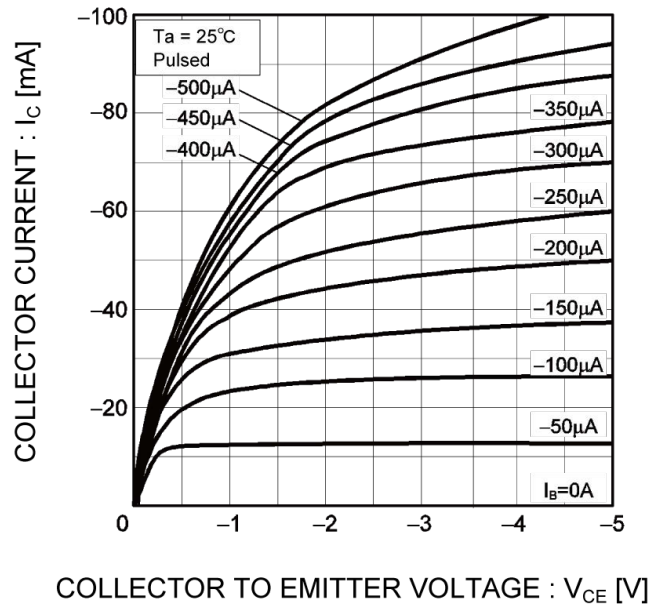


Fig.3 DC Current Gain vs. Collector Current (I)

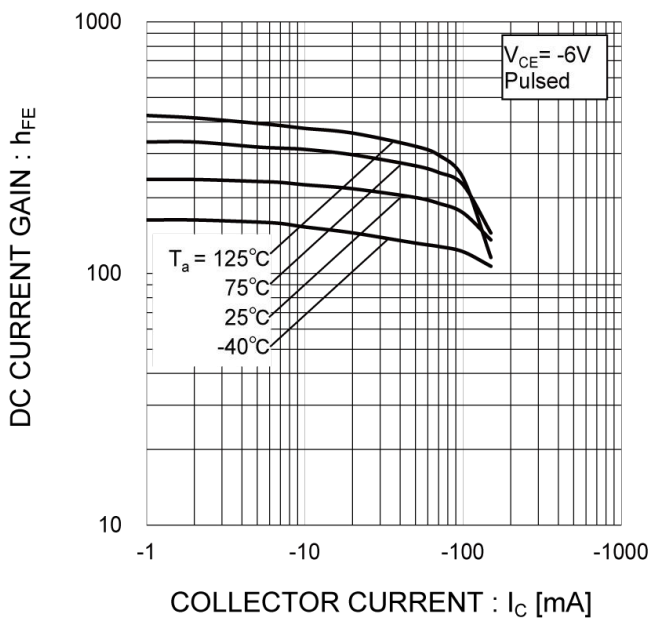
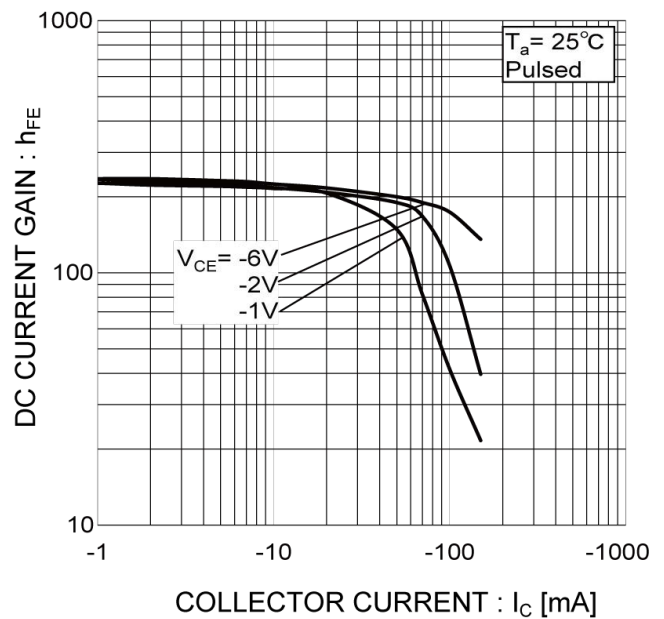


Fig.4 DC Current Gain vs. Collector Current (II)



●Electrical characteristic curves($T_a=25^\circ\text{C}$ <For Tr1(PNP)>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

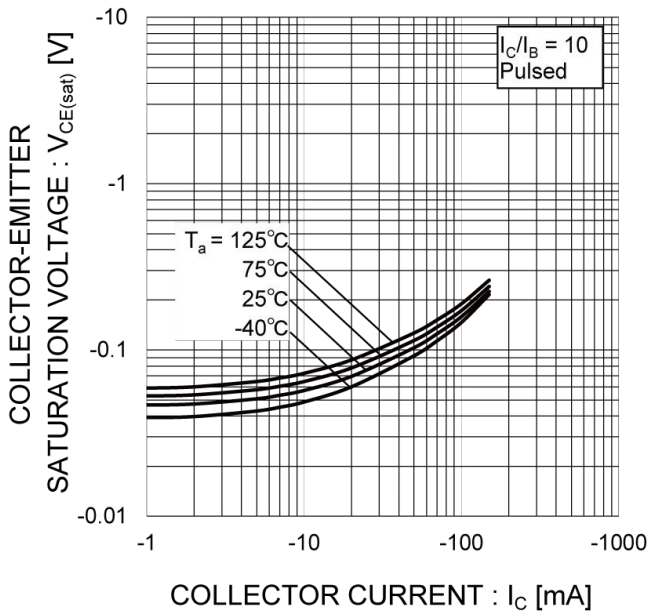


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

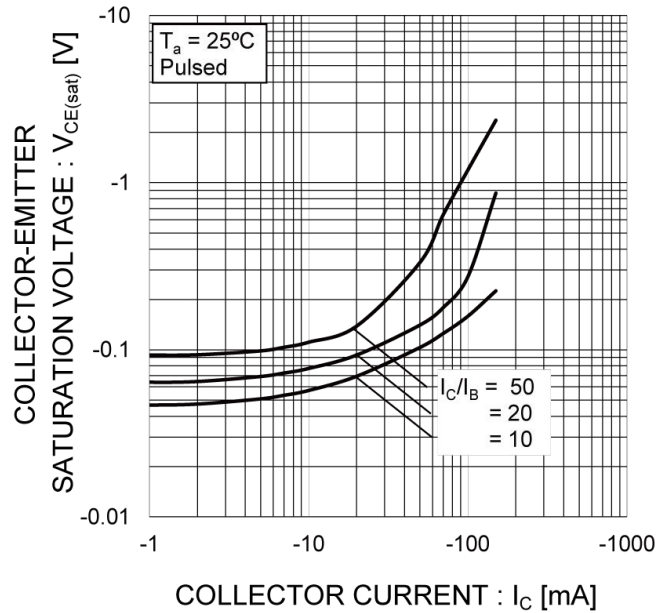


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current (I)

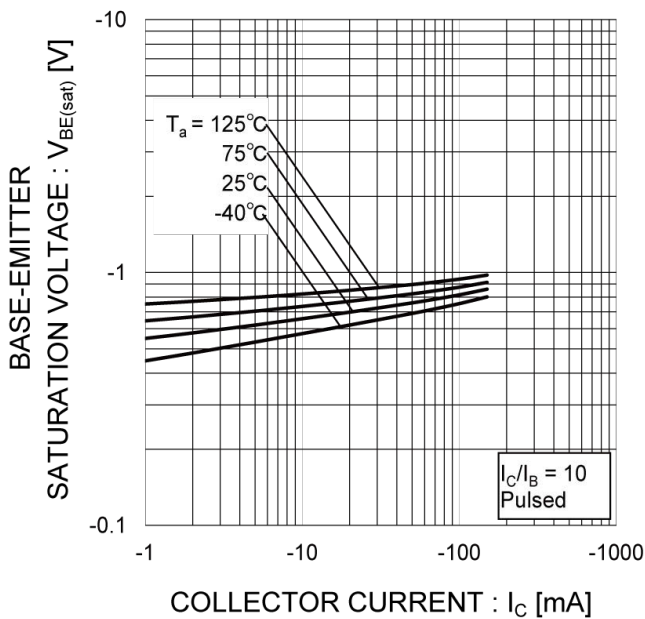
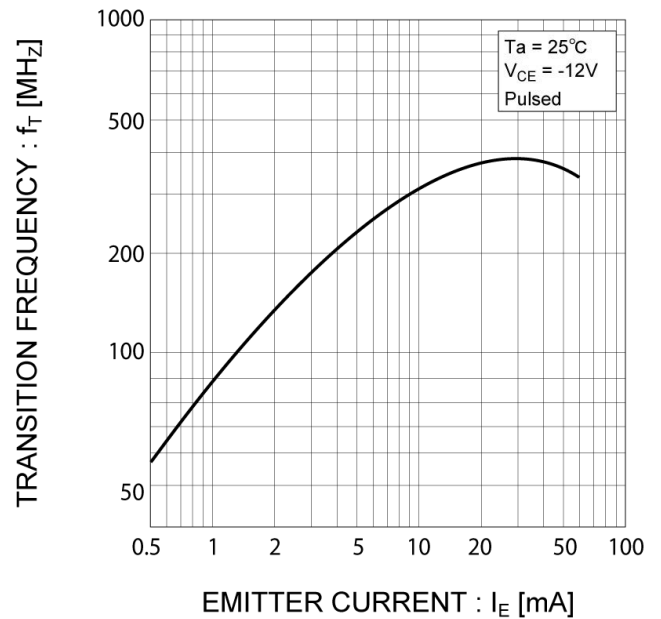


Fig.8 Gain Bandwidth Product vs. Emitter Current



●Electrical characteristic curves($T_a=25^\circ\text{C}$) <For Tr1(PNP)>

Fig.9 Collector Output Capacitance vs. collector-Base Voltage
Emitter Input Capacitance vs. Emitter-Base Voltage

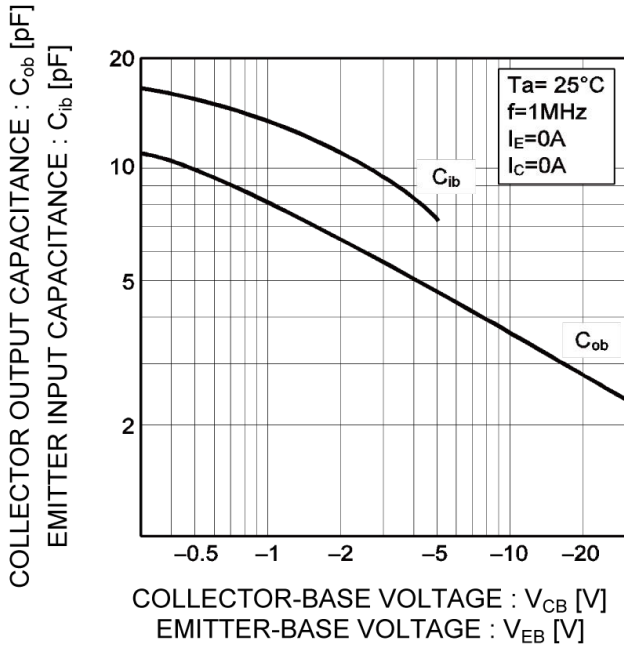


Fig.10 Safe Operating Area

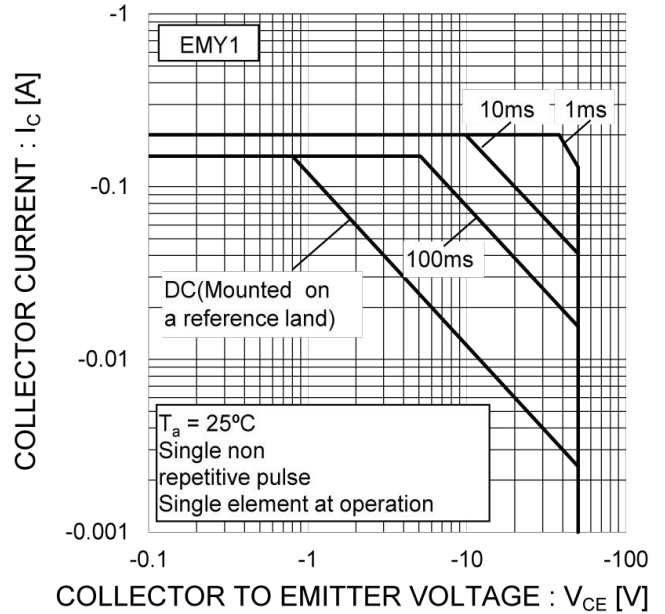


Fig.11 Safe Operating Area

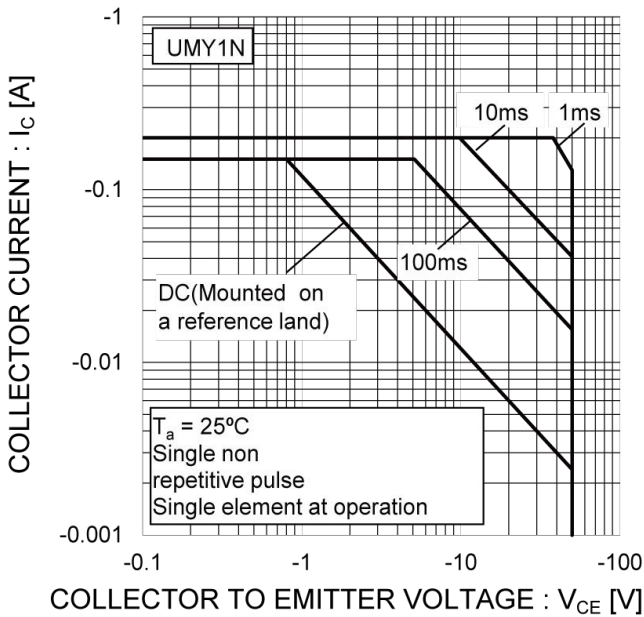
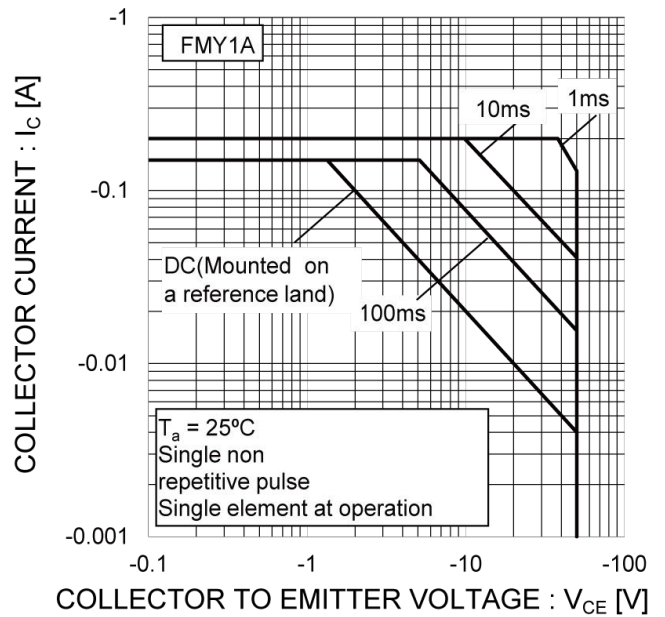


Fig.12 Safe Operating Area



●Electrical characteristic curves($T_a=25^{\circ}\text{C}$ <For Tr2(NPN)>

Fig.13 Ground Emitter Propagation Characteristics

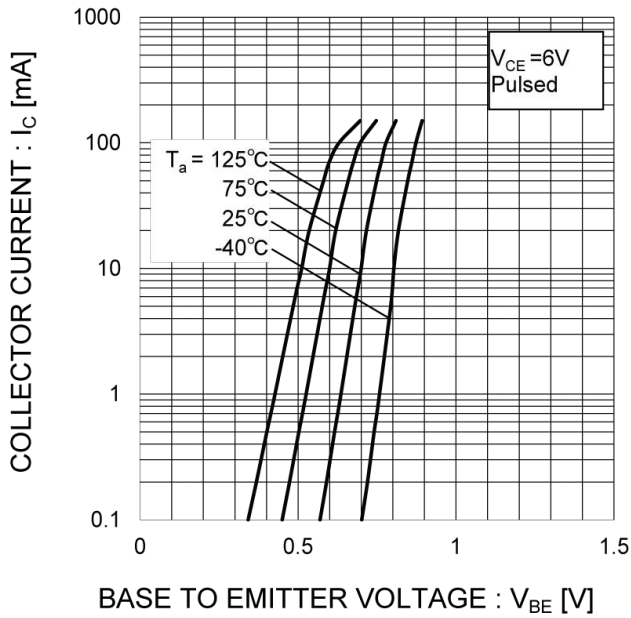


Fig.14 Grounded Emitter Output Characteristics

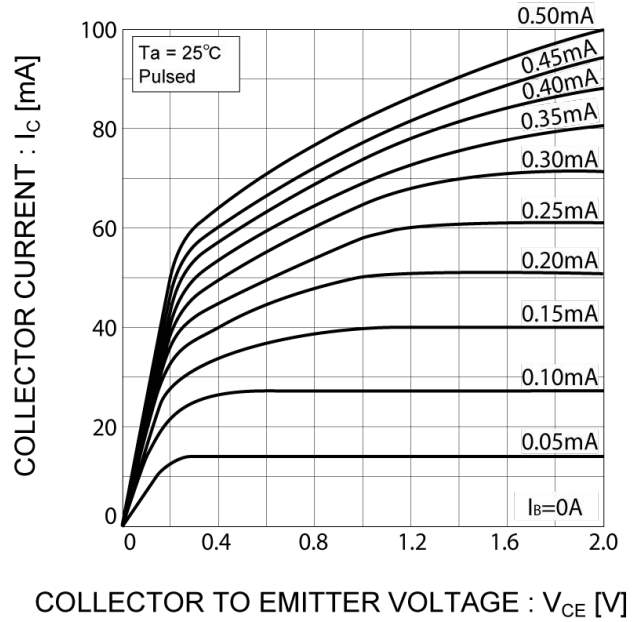


Fig.15 DC Current Gain vs. Collector Current (I)

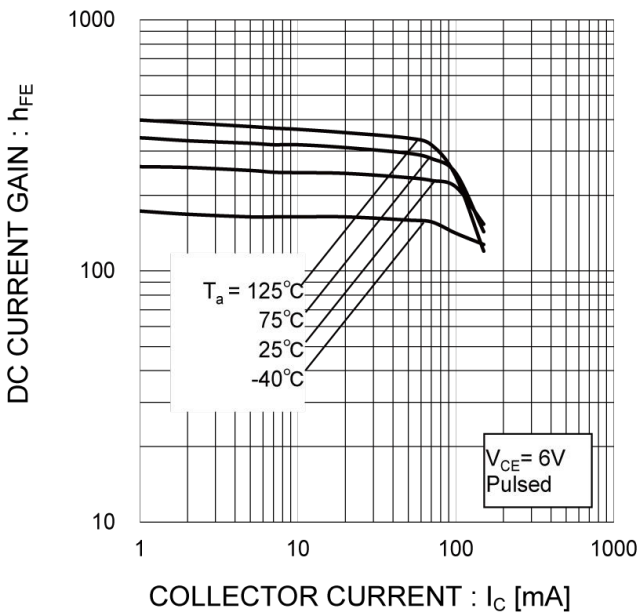
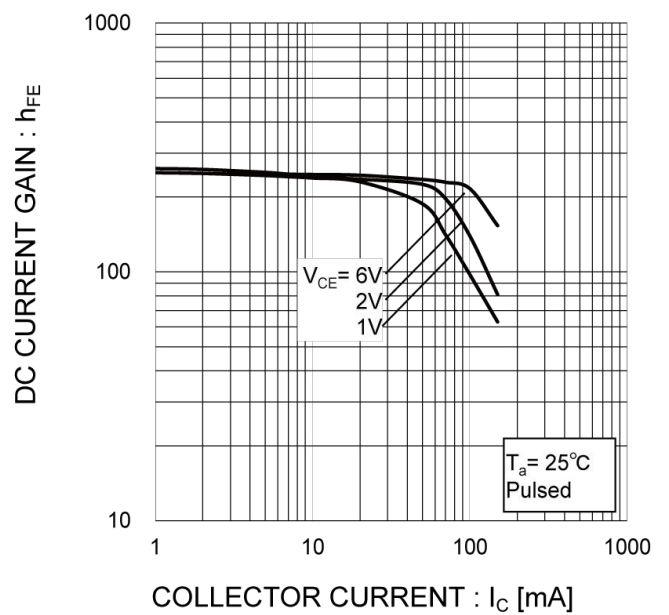


Fig.16 DC Current Gain vs. Collector Current (II)



●Electrical characteristic curves ($T_a = 25^\circ\text{C}$) <For Tr2(NPN)>

Fig.17 Collector-Emitter Saturation Voltage vs. Collector Current(I)

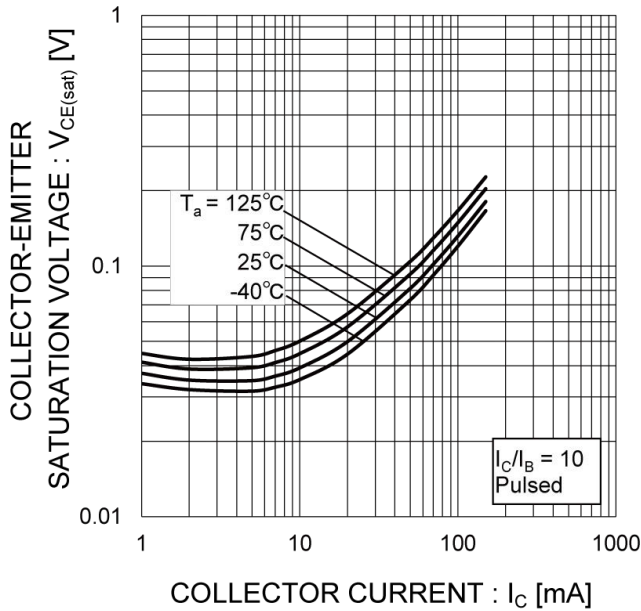


Fig.18 Collector-Emitter Saturation Voltage vs. Collector Current(II)

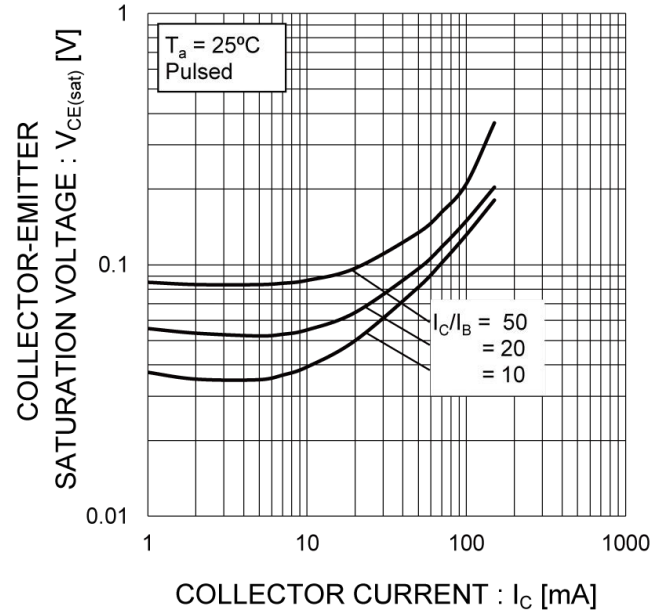


Fig.19 Base-Emitter Saturation Voltage vs. Collector Current (I)

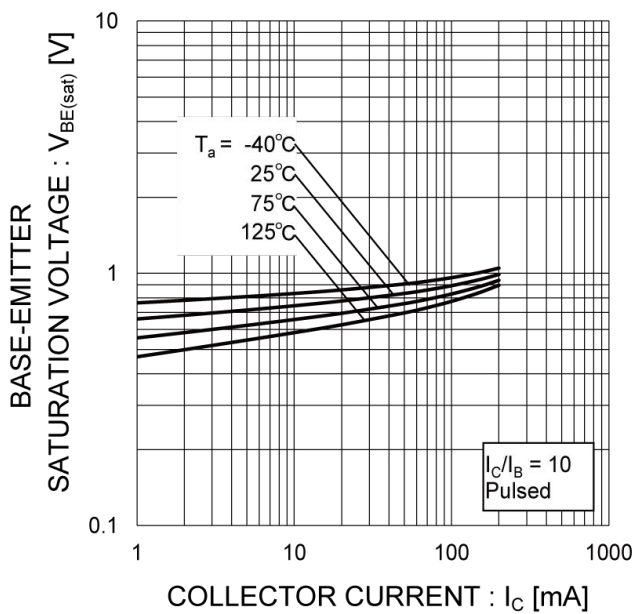
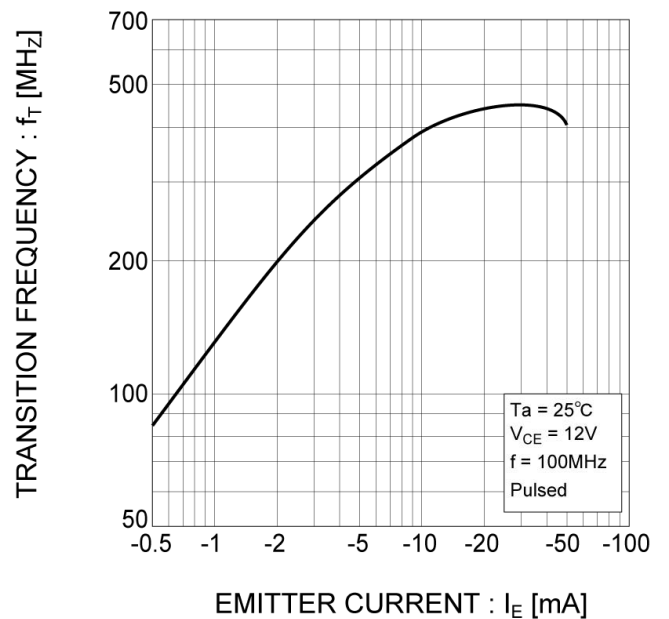


Fig.20 Gain Bandwidth Product vs. Emitter Current



●Electrical characteristic curves($T_a = 25^\circ\text{C}$) <For TR2(NPN)>

Fig.21 Collector Output Capacitance vs. collector-Base Voltage
Emitter Input Capacitance vs. Emitter-Base Voltage

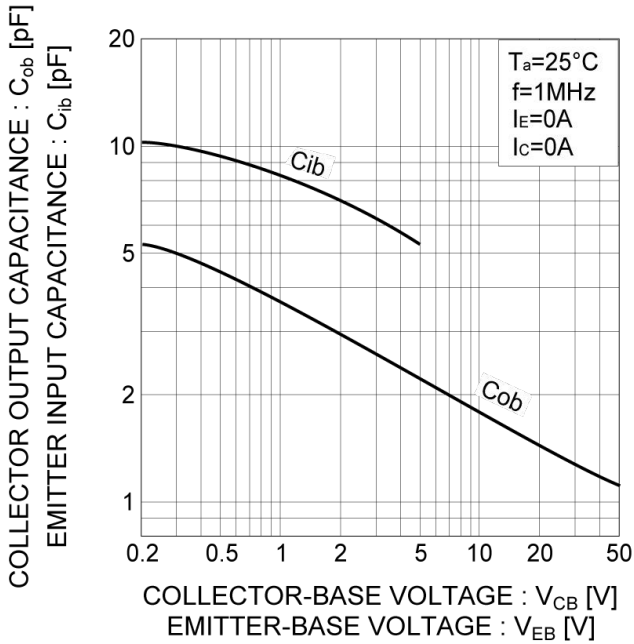


Fig.22 Safe Operating Area

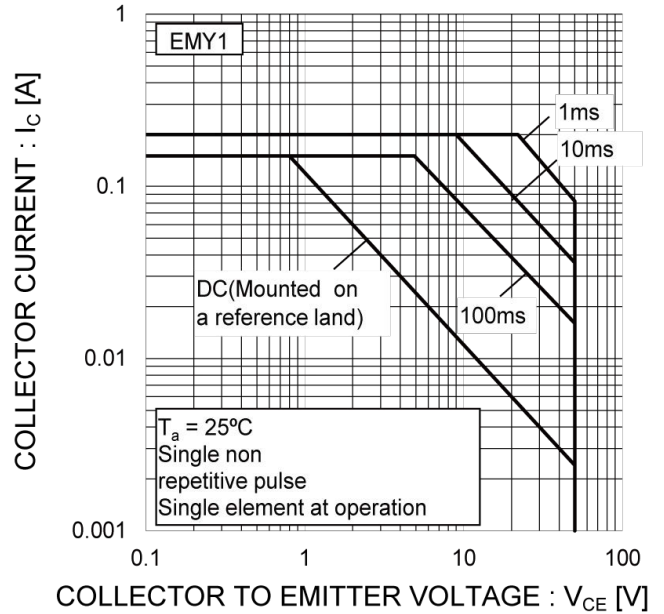


Fig.23 Safe Operating Area

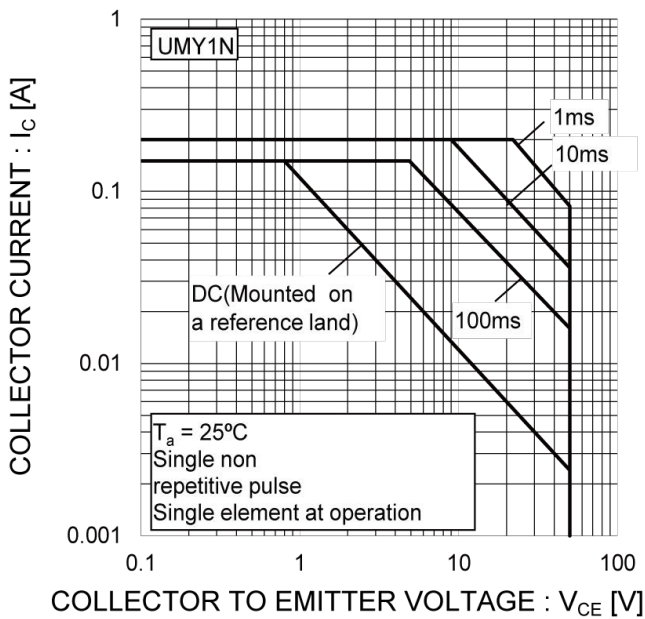
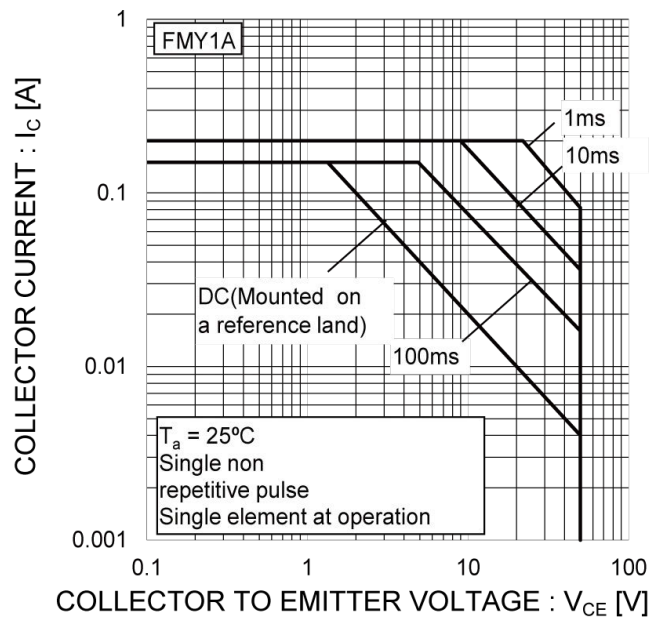
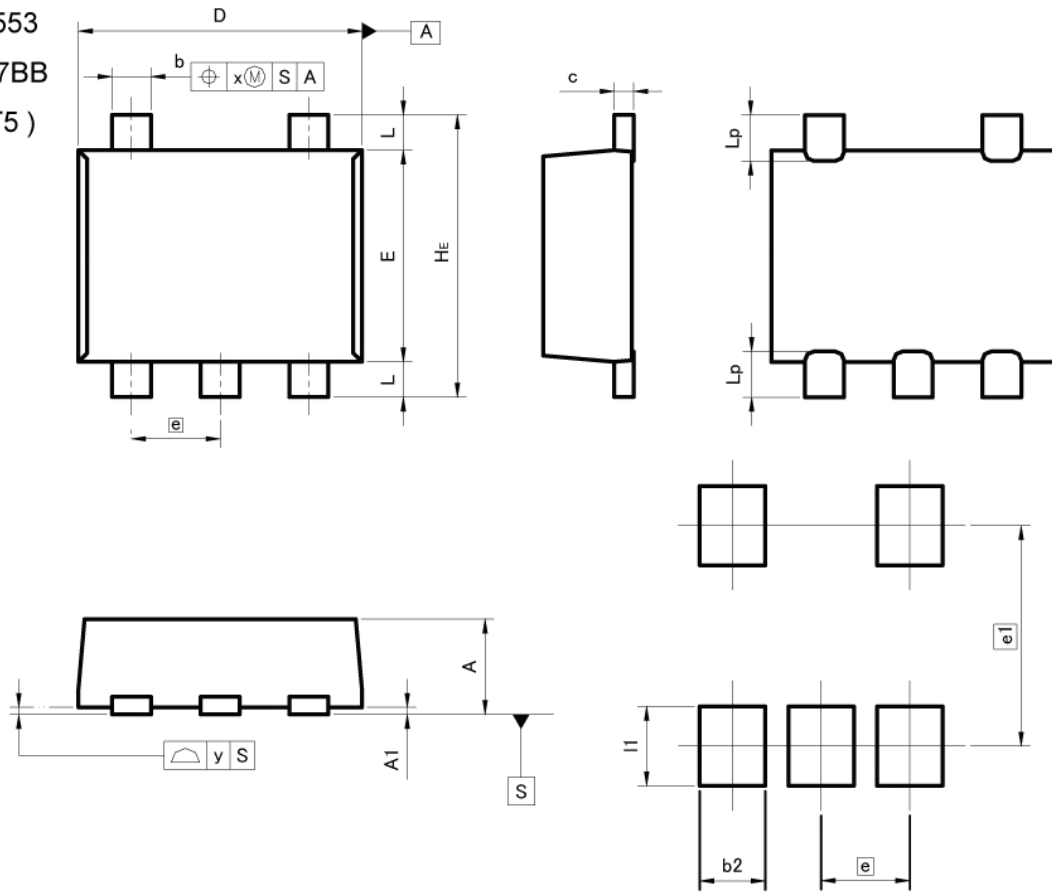


Fig.24 Safe Operating Area



●Dimensions

SOT-553
SC-107BB
(EMT5)



Pattern of terminal position areas
[Not a pattern of soldering pads]

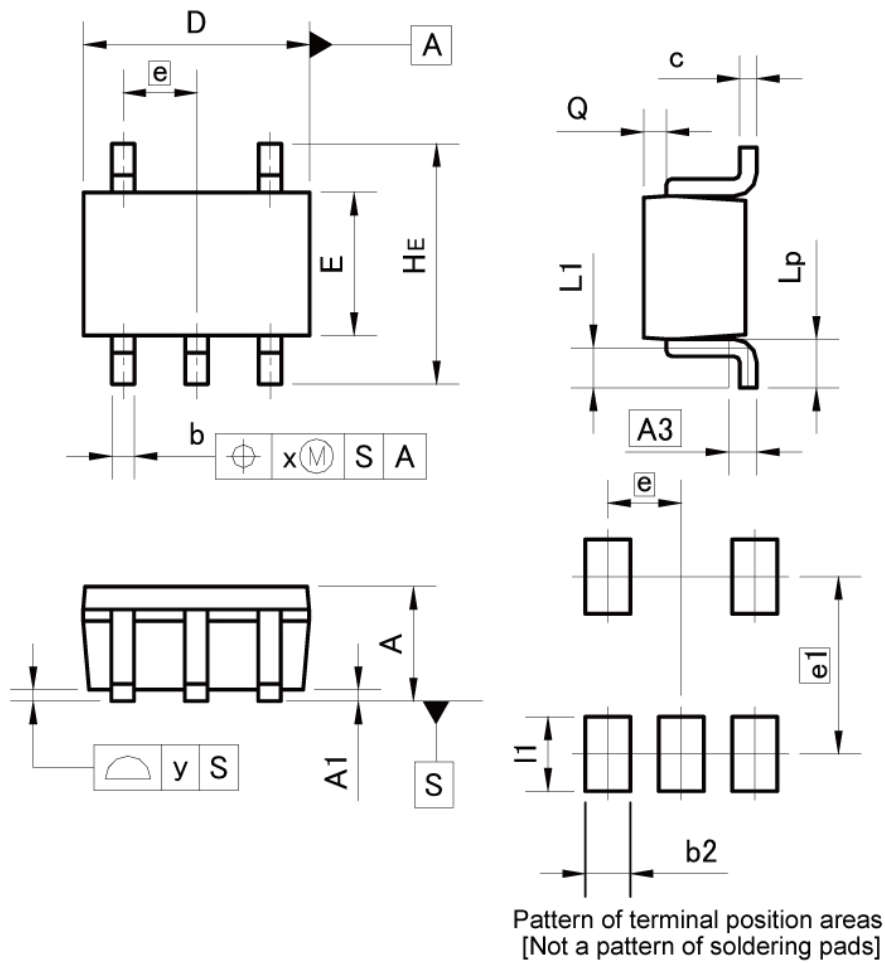
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
e1	1.25		0.049	
I1	-	0.45	-	0.018

Dimension in mm/inches

●Dimensions

SOT-353
SC-88A
(UMT5)



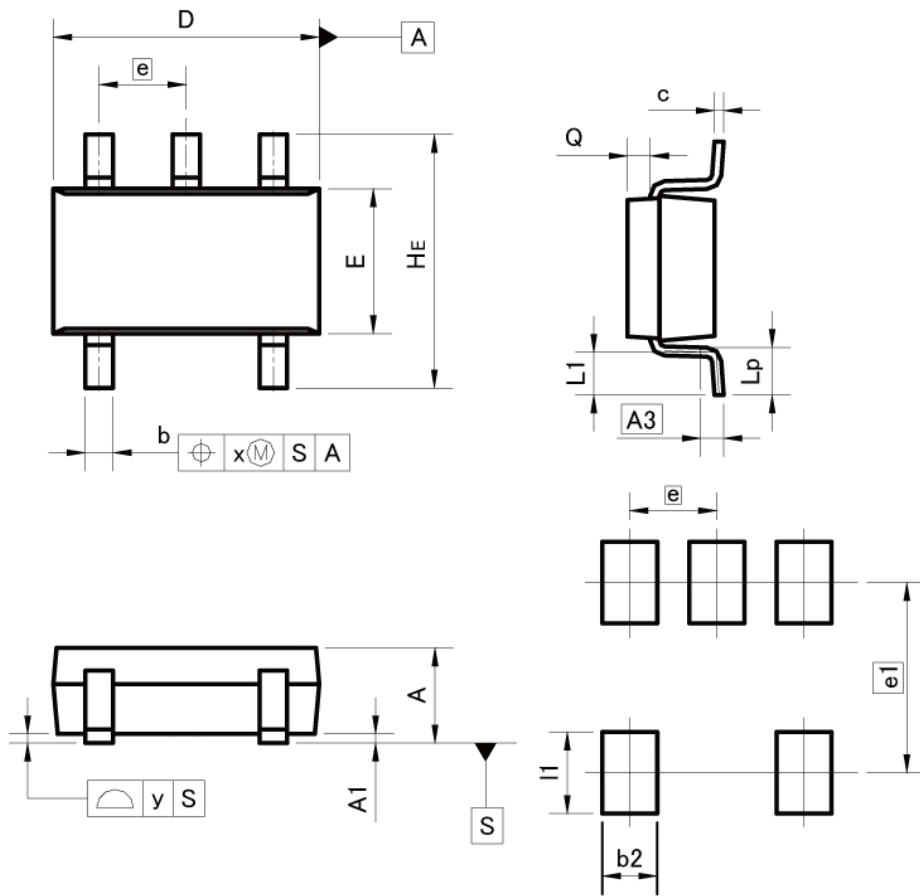
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.40	-	0.016
e1	1.55		0.061	
l1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions

SOT-25
SC-74A
(SMT5)



Pattern of terminal position areas
[Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.25	0.40	0.010	0.016
c	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.20	-	0.008
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.60	-	0.024
e1	2.10		0.083	
I1	-	0.90	-	0.035

Dimension in mm/inches

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